Schottky Diode

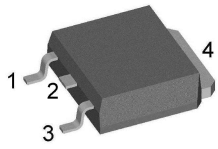
V_{RRM}	=	45 V
I_{FAV}	=	6 A
V_F	=	0.5 V

High Performance Schottky Diode
Low Loss and Soft Recovery
Single Diode

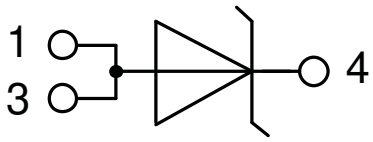
Part number

DSS6-0045AS

Marking on Product: 6Y045AS



Backside: cathode



Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-252 (DPak)

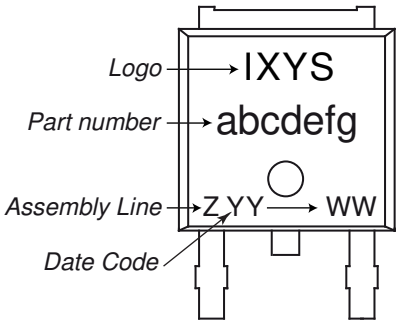
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Schottky				Ratings			
Symbol	**Definition**	**Conditions**		**min.**	**typ.**	**max.**	**Unit**
V_{RSM}	*max. non-repetitive reverse blocking voltage*		T_{VJ} = 25°C			45	V
V_{RRM}	*max. repetitive reverse blocking voltage*		T_{VJ} = 25°C			45	V
I_R	*reverse current, drain current*	V_R = 45 V	T_{VJ} = 25°C			250	µA
		V_R = 45 V	T_{VJ} = 125°C			2.5	mA
V_F	*forward voltage drop*	I_F = 6 A	T_{VJ} = 25°C			0.63	V
		I_F = 12 A				0.71	V
		I_F = 6 A	T_{VJ} = 125°C			0.50	V
		I_F = 12 A				0.59	V
I_{FAV}	*average forward current*	T_C = 165°C	T_{VJ} = 175°C			6	A
		rectangular d = 0.5					
V_{F0}	*threshold voltage* } *for power loss calculation only*		T_{VJ} = 175°C			0.35	V
r_F	*slope resistance* }					13.9	mΩ
R_{thJC}	*thermal resistance junction to case*					3	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.50		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			50	W
I_{FSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine; V_R = 0 V	T_{VJ} = 45°C			120	A
C_J	*junction capacitance*	V_R = 5 V f = 1 MHz	T_{VJ} = 25°C		497		pF

Package TO-252 (DPak)			Ratings			
Symbol	**Definition**	**Conditions**	**min.**	**typ.**	**max.**	**Unit**
I_{RMS}	*RMS current*	per terminal [1]			20	A
T_{VJ}	*virtual junction temperature*		-55		175	°C
T_{op}	*operation temperature*		-55		150	°C
T_{stg}	*storage temperature*		-55		150	°C
Weight				0.3		g
F_C	*mounting force with clip*		20		60	N

[1] I_{RMS} is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2). In case of (1) and a product with multiple pins for one chip-potential, the current capability can be increased by connecting the pins as one contact.

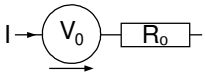
Product Marking



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSS6-0045AS-TRL	6Y045AS	Tape & Reel	2500	497878
Alternative	DSS6-0045AS-TUB	6Y045AS	Tube	70	525014

Equivalent Circuits for Simulation

** on die level* T_{VJ} = 175 °C



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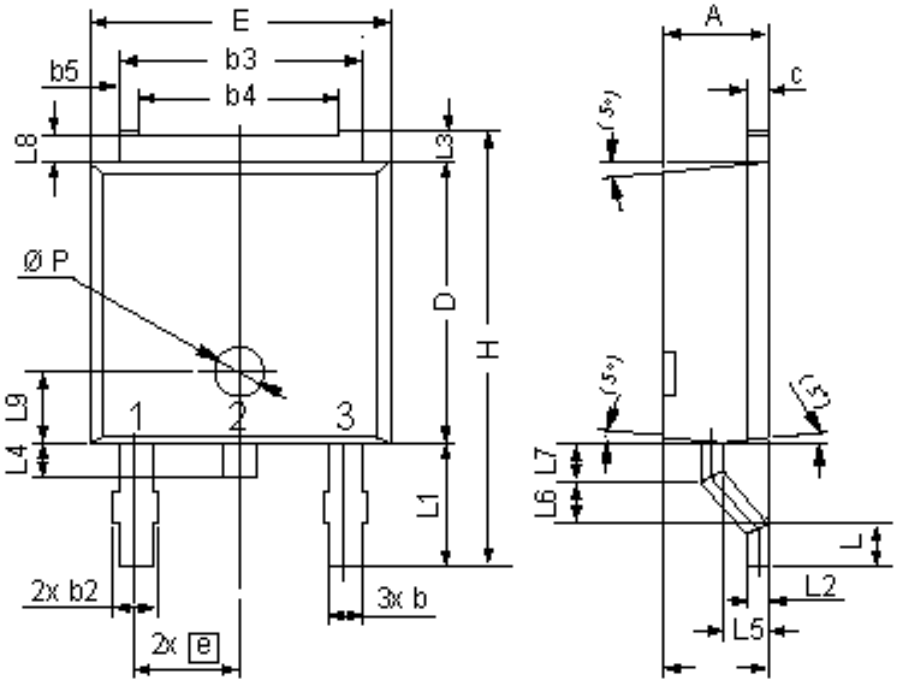
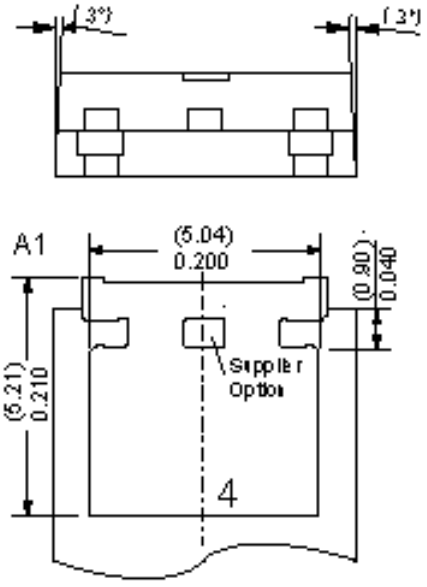
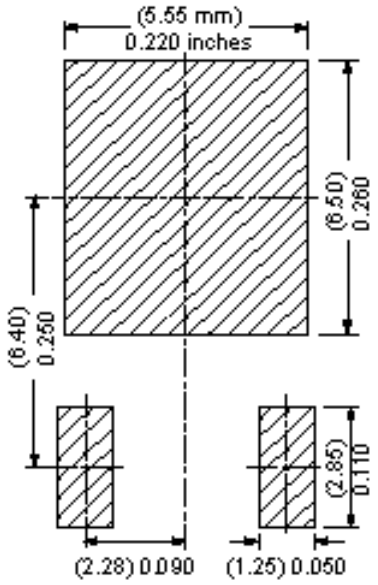
$V_{0\,max}$	*threshold voltage*	0.35	V
$R_{0\,max}$	*slope resistance **	10.7	mΩ

Outlines TO-252 (DPak)

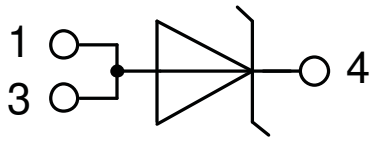


Dim.	Millimeters		Inches	
	min	max	min	max
A	2.20	2.40	0.087	0.094
A1	2.10	2.50	0.083	0.098
b	0.66	0.86	0.026	0.034
b2	-	0.96	-	0.038
b3	5.04	5.64	0.198	0.222
b4	4.34 BSC		0.171 BSC	
b5	0.50 BSC		0.020 BSC	
c	0.40	0.86	0.016	0.034
D	5.90	6.30	0.232	0.248
E	6.40	6.80	0.252	0.268
e	2.10	2.50	0.083	0.098
H	9.20	10.10	0.362	0.398
L	0.55	1.28	0.022	0.050
L1	2.50	2.90	0.098	0.114
L2	0.40	0.60	0.016	0.024
L3	0.50	0.90	0.020	0.035
L4	0.60	1.00	0.024	0.039
L5	0.82	1.22	0.032	0.048
L6	0.79	0.99	0.031	0.039
L7	0.81	1.01	0.032	0.040
L8	0.40	0.80	0.016	0.031
L9	1.50 BSC		0.059 BSC	
Ø P	1.00 BSC		0.039 BSC	





Recommended
min. foot print



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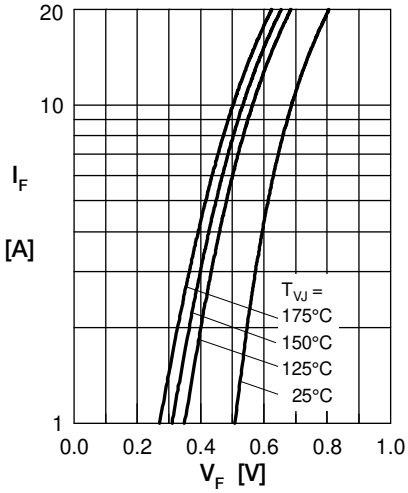

Fig. 1 Max. forward voltage drop characteristics

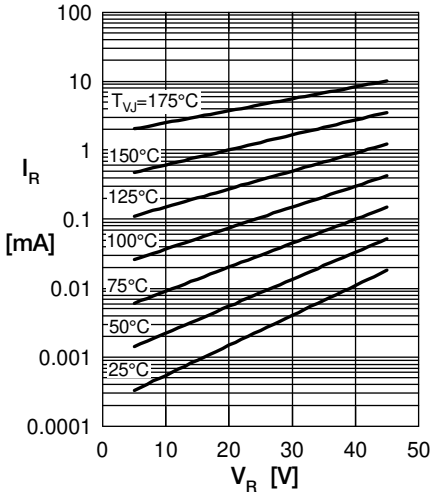

Fig. 2 Typ. reverse current I_R vs. reverse voltage V_R

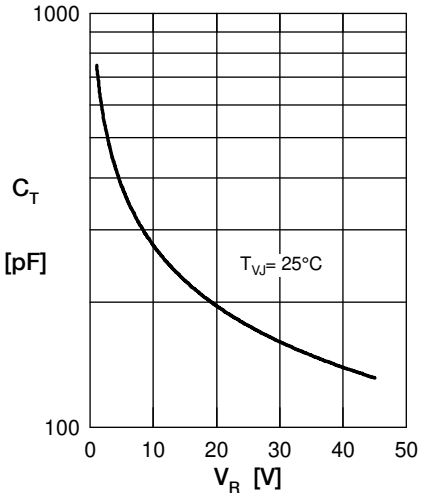

Fig. 3 Typ. junction capacitance C_T vs. reverse voltage V_R

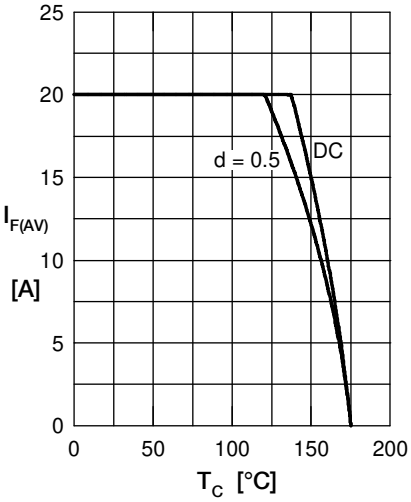

Fig. 4 Average forward current $I_{F(AV)}$ vs. case temp. T_C

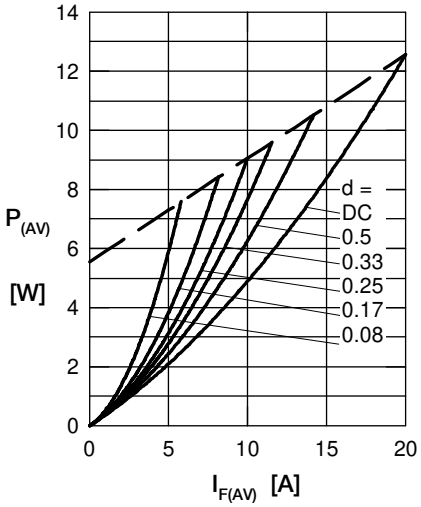

Fig. 5 Forward power loss characteristics

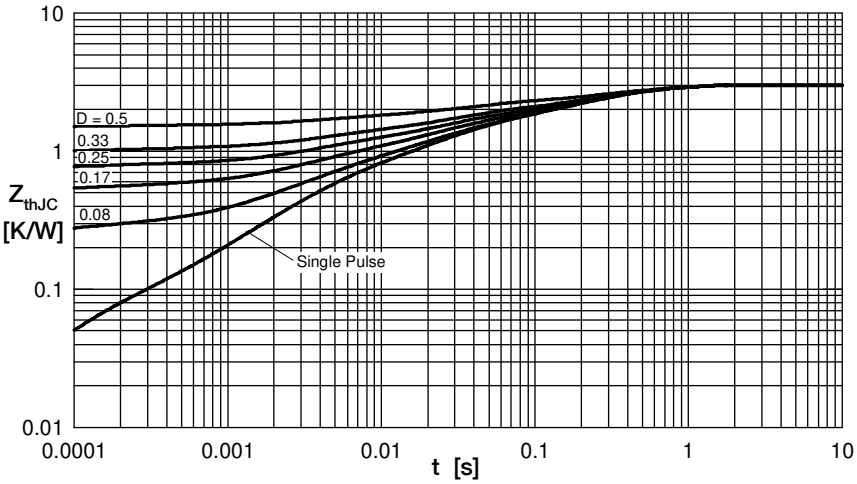

Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode